VS-HFA140FA120

Vishay Semiconductors



HEXFRED[®] Ultrafast Soft Recovery Diode, 140 A



PRIMARY CHARACTERISTICS				
V _R	1200 V			
V _F (typical)	2.8 V			
t _{rr} (typical)	48 ns			
$I_{F(DC)}$ at T_C , per module	140 A at 74 °C			
$I_{F(AV)}$ at T_{C} , per module	140 A at 46 °C			
Package	SOT-227			

FEATURES

- · Fast recovery time characteristic
- · Electrically isolated base plate
- Large creepage distance between terminal
- · Simplified mechanical designs, rapid assembly
- · Designed and qualified for industrial level
- UL approved file E78996
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

The dual diode series configuration VS-HFA140FA120 is used for output rectification or freewheeling/clamping operation and high voltage application.

The semiconductor in the SOT-227 package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built.

These modules are intended for general applications such as HV power supplies, electronic welders, motor control and inverters.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V _R		1200	V
Continuous forward current per leg	I_	T _C = 74 °C	70	
per module	I _F		140	А
Single pulse forward current	I _{FSM}	T _J = 25 °C	350	
Maximum neuror dissinction ner les	P _D	T _C = 25 °C	357	W
Maximum power dissipation, per leg		T _C = 100 °C	143	vv
RMS isolation voltage	VISOL	Any terminal to case, t = 1 minute	2500	V
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C

ELECTRICAL SPECIFICATIONS ($T_J = 25$ °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA	1200	-	-	
Forward voltage, per leg	V _{FM}	I _F = 60 A	-	2.8	4.0	V
		I _F = 120 A	-	3.6	5.3	
		I _F = 60 A, T _J = 125 °C	-	2.7	-	
		I _F = 60 A, T _J = 150 °C	-	2.65	-	
Reverse leakage current, per leg		V _R = V _R rated	-	2.0	75	μA
	I _{RM}	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	1.6	5	mA
		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	5	10	IIIA

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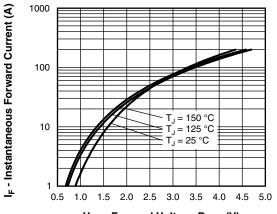


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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}; \text{ d}I_F/\text{d}t$	I _F = 1 A; dI _F /dt = 200 A/μs; V _R = 30 V		48	-	
Reverse recovery time, per leg	t _{rr}	T _J = 25 °C		-	145	-	ns A
		T _J = 125 °C	l _F = 50 A dl _F /dt = - 200 A/µs	-	218	-	
Deale recorder a surrent a sur la s	I _{RRM}	$T_J = 25 \ ^\circ C$		-	13	-	
Peak recovery current, per leg		IRRM	T _J = 125 °C	$V_{\rm R} = 200 \text{ V}$	-	18	-
Reverse recovery charge, per leg	0	T _J = 25 °C	v _R = 200 v	-	910	-	nC
	Q _{rr}	T _J = 125 °C		-	1920	-	nc
Junction capacitance, per leg	CT	V _R = 1200 V		-	27	-	pF

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Junction to case, single leg conducting	Б		-	-	0.35	
Junction to case, both legs conducting	R _{thJC}		-	-	0.175	°C/W
Case to heatsink	R _{thCS}	Flat, greased surface	-	0.05	-	
Weight			-	30	-	g
Mounting torque		Torque to terminal	-	-	1.1 (9.7)	Nm (lbf.in)
Mounting torque		Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)
Case style				S	OT-227	



V_{FM} - Forward Voltage Drop (V)

Fig. 1 - Typical Forward Voltage Drop Characteristics

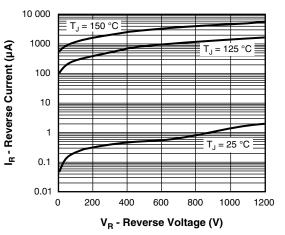
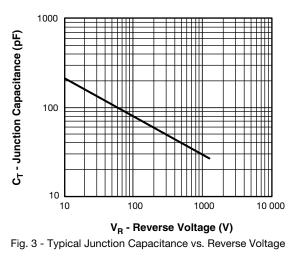
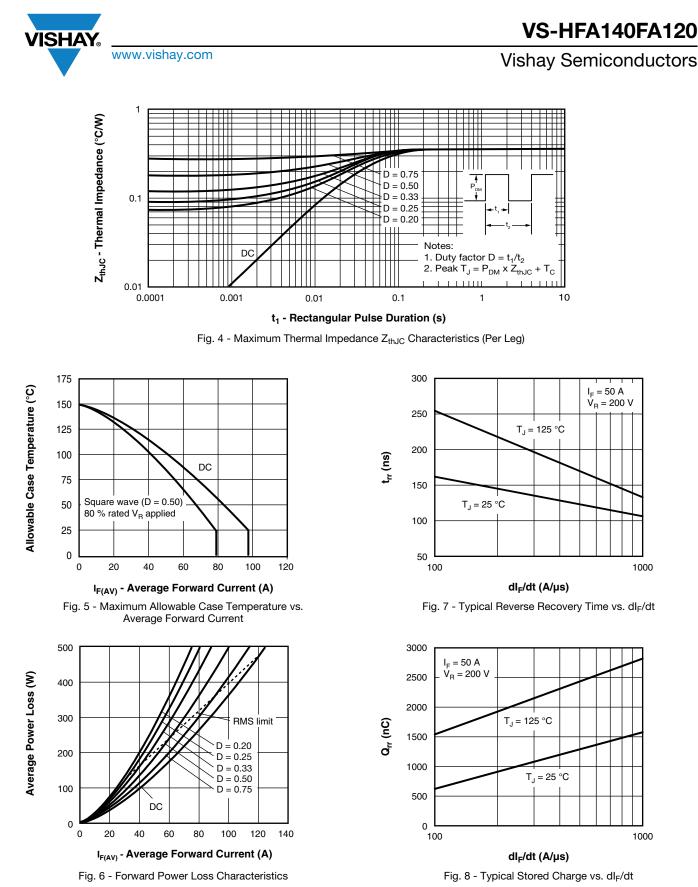


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 5); Pd_{REV} = inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = rated V_R

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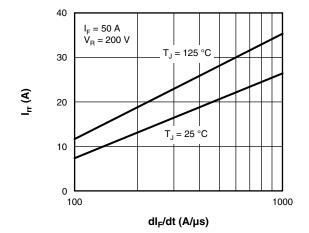


Fig. 9 - Typical Peak Recovery Current vs. dI_F/dt

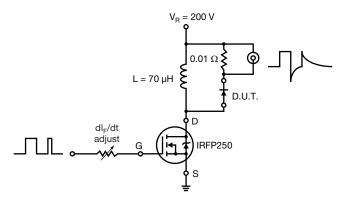


Fig. 10 - Reverse Recovery Parameter Test Circuit

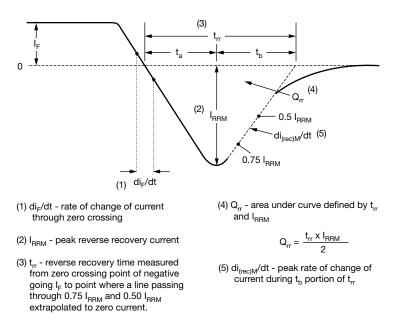


Fig. 11 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

VS-HF F **Device code** Α 140 120 Α (2)(3) 5 (6)1 (4)7 1 2 3 4 5 Vishay Semiconductors product HEXFRED[®] family Process designator (A = electron irradiated) Average current (140 = 140 A) Circuit configuration (two separate diodes, parallel pin-out) 6 Package indicator (SOT-227 standard insulated base) 7 Voltage rating (120 = 1200 V)

CIRCUIT CONFIGURATION					
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING			
Two separate diodes, parallel pin-out	F	Lead Assignment 4 1 1 1 1 1 1 1 1 1 1 1 1 1			

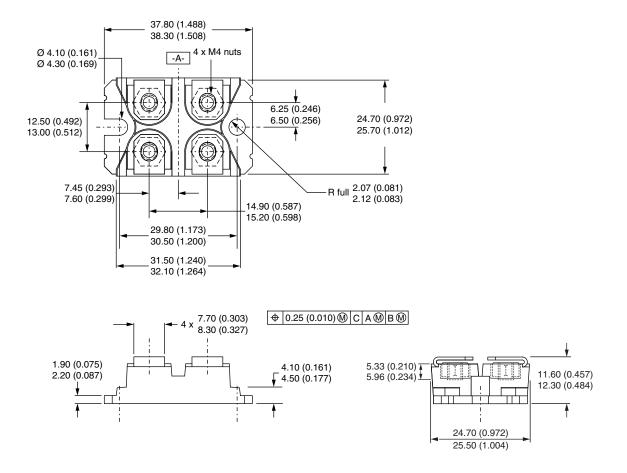
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95423		
Part marking information	www.vishay.com/doc?95425		

Vishay Semiconductors



SOT-227 Generation 2

DIMENSIONS in millimeters (inches)



Note

• Controlling dimension: millimeter



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